L Number	Hits	Search Text	DB	Time stamp
-	25	(strain$3 same (porous near5 crystal$5)) and light	USPAT; US-PGPUB	2004/06/23 16:55
-	27	(strain$3 same (porous near5 crystal$5)) and (light radiation)	USPAT; US-PGPUB	2004/06/23 17:04
-	1887	(359/299,244,290,321,824).ccls. (310/311).ccls.	USPAT; US-PGPUB	2004/06/23 17:04
-	19	((359/299,244,290,321,824).ccls. (310/311).ccls.) and ((light radiation) with strain$3)	USPAT; US-PGPUB	2004/06/23 17:11
-	19	((359/299,244,290,321,824).ccls. (310/311).ccls.) and ((light radiation) with strain$3)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/06/23 17:12
-	8820	((light radiation) with strain$3)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/06/23 17:13
-	15	(((light radiation) with strain$3)) and (porous near5 crystal$5)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/06/23 17:15
-	23	(((light radiation) with strain$3)) and (porous near5 (silicon si))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/06/23 17:15
-	12	((((light radiation) with strain$3)) and (porous near5 (silicon si))) not (((light radiation) with strain$3)) and (porous near5 crystal$5))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/06/23 17:17
-	526	piezooptic$2 or (piezo near2 optic$2)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/06/23 17:18
-	263	(piezooptic$2 or (piezo near2 optic$2)) and crystal$5	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/06/23 17:18
-	112	((piezooptic$2 or (piezo near2 optic$2)) and crystal$5) and strain$3	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/06/23 17:19
-	7	(((piezooptic$2 or (piezo near2 optic$2)) and crystal$5) and strain$3) and porous	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/06/23 17:23
-	4	(US-5569626-$ or US-5405786-$ or US-5387803-$ or US-5376818-$).did.	USPAT	2004/06/23 17:22
-	4	((US-5569626-$ or US-5405786-$ or US-5387803-$ or US-5376818-$).did.) and (strain$3 same (light radiation))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/06/23 17:25

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-	437	438/57.ccls.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/06/23 17:25
-	32	438/57.ccls. and strain$3	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/06/23 17:25
-	14	438/57.ccls. and (strain$3 same (light radiation))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/06/23 17:26
-	14	(438/57.ccls. and (strain$3 same (light radiation))) and (crystal$5 silicon)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/06/23 17:26
-	1	((438/57.ccls. and (strain$3 same (light radiation))) and (crystal$5 silicon)) and porous	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/06/23 17:26
-	10	4524294.URPN.	USPAT	2004/06/23 17:56
-	16966	ferroelectric	USPAT; US-PGPUB	2004/06/23 17:58
-	166	ferroelectric same porous	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/06/23 18:02
-	40	(ferroelectric same porous) same crystal$8	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/06/23 18:01
-	1092	(cadmium near2 sulfide) same crystal$8	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/06/23 18:01
-	621	(cadmium near2 sulfide) with crystal$8	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/06/23 18:01
-	2	(cadmium near2 sulfide) with (porous with crystal$8)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/06/23 18:01
-	104	ferroelectric with porous	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/06/23 18:02
-	10	ferroelectric with porous with crystal$8	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/06/23 18:02

-	2053785	porous (silicon crystal$5)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/06/24 11:30
-	7577	porous adj2 (silicon crystal$5)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/06/24 11:31
-	5227	porous adj2 (silicon)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/06/24 11:31
-	4524	porous adj (silicon)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/06/24 11:31
-	606	(porous adj (silicon)) same light	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/06/24 11:31
-	445	(porous adj (silicon)) with light	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/06/24 11:40
-	39807	ferroelectric$2	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/06/24 11:40
-	619	ferroelectric$2 and (remanent near3 polariz$8)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/06/24 11:41
-	1	(ferroelectric$2 and (remanent near3 polariz$8)) and (length with depend$3 with photoelectric with effect)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/06/24 11:41
-	1	(ferroelectric$2 and (remanent near3 polariz$8)) and (photoelectric with effect)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/06/24 11:42
-	1	(ferroelectric$2 and (remanent near3 polariz$8)) and (photoelectric$2 with effect)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/06/24 11:42
-	323	piezooptic$2 or (piezo adj2 optic$2)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/06/24 16:28
-	14	(piezooptic$2 or (piezo adj2 optic$2)) and porous	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/06/24 16:28

		7	(piezooptic$2 or (piezo adj2 optic$2)) and (porous with (silicon or crystal$5))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/06/24 16:28
-		7	((piezooptic$2 or (piezo adj2 optic$2)) and (porous with (silicon or crystal$5))) and light	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/06/24 16:29